

FAST [10017389.wsp 1]

File View Edit Tools Window Help

☐ Drafts  
☐ Pending  
☒ Active  
     L1: (0) ("semiconductor  
     L2: (6612) semiconducto  
     L3: (352) 2 and group a  
     L4: (33) 2 and group ad  
     L5: (86) 3 and Al\$Ga\$N  
     L6: (30) 3 and Al\$Ga\$N  
☐ Failed  
☐ Saved  
☐ Favorites  
☐ Tagged (0)  
☐ UDC  
☐ Queue  
☐ Trash

Search

USPAT:EPO:JPO ☒ Plurals  
 Default operator: OR ☒ Highlight all hit terms initially

3 and Al\$Ga\$N and Al\$Ga\$In\$N

	U	1	Document ID	Issue Dat	Pages	Title	Current OR	Current XI
1	<input type="checkbox"/>	<input type="checkbox"/>	US 6579780	20030617	40	Method for growing a compound semiconductor.	438/479	438/46;
2	<input type="checkbox"/>	<input type="checkbox"/>	B2 US 6542526	20030401	39	Optical information processor and semicondu	372/45	438/483 372/46
3	<input checked="" type="checkbox"/>	<input type="checkbox"/>	B1 US 6537838	20030325	7	Forming semiconductor structures including ac	438/22	257/96; 438/46
4	<input checked="" type="checkbox"/>	<input type="checkbox"/>	B2 US 6530991	20030311	28	Method for the formation of semiconduc	117/89	117/103; 117/106;
5	<input checked="" type="checkbox"/>	<input type="checkbox"/>	B1 US 6526083	20030225	15	Two section blue laser diode with reduced outp	372/50	438/48
6	<input checked="" type="checkbox"/>	<input type="checkbox"/>	B1 US 6508879	20030121	9	Method of fabricating group III-V nitride com	117/104	117/101; 117/952
7	<input checked="" type="checkbox"/>	<input type="checkbox"/>	B1 US 6455340	20020924	8	Method of fabricating GaN semiconductor struc	438/31	438/39; 438/47
8	<input checked="" type="checkbox"/>	<input type="checkbox"/>	B1 US 6379985	20020430	21	Methods for cleaving facets in III-V nitride	438/33	257/E29.00 4;
9	<input checked="" type="checkbox"/>	<input type="checkbox"/>	B1 US 6345063	20020205	14	Algainn elog led and laser diode structures	372/45	257/14; 257/E33.02
10	<input checked="" type="checkbox"/>	<input type="checkbox"/>	B1 US 6342405	20020129	21	Methods for forming group III-arsenide-nitr	438/46	257/E33.02 8
11	<input checked="" type="checkbox"/>	<input type="checkbox"/>	B1 US 6285696	20010904	16	Algainn pendeoeptitaxy led and laser diode str	438/22	257/14; 257/E33.02